Samsung 16GB DDR4 2400MHz memory module 1 x 16 GB 288-pin DIMM ECC

Gamintojas: **SAMSUNG** · Modelis: **M393A2K40BB1-CRC** · EAN: **4260580370474** · Prekės kodas: **1011716**



219,91 €

Kaina su PVM

Be PVM: **181,74 €**

Sandėlyje

Prekė internetu

Nuskenuokite kodą arba apsilankykite www.shopro.lt

Pagrindinės savybės

- ✓ PC/Server 16 GB DDR4
- ✓ 288-pin DIMM 1 x 16 GB
- ✓ CAS latency: 17
- ✓ 1.2 V
- ✓ ECC

Aprašymas

Boost your PC’s performance to new levels.
You need the right expert for the right PC memory solution.
Samsung is a leader in the DRAM market, with our DRAM being selected by most OEMs for many years.
Embrace the cutting-edge Samsung DDR4 to take your PC to a new dimension of high speed and low energy performance.

Improved bandwidth for high-end applications.
With PC applications becoming more critical and complex, personal computing has set its toughest demands yet. PCs today need to provide exceptional speed to deliver the performance required.

Samsung 2xnm DDR4 UDIMM and SODIMM enable initial bandwidth of 2,400 Mbps, which can achieve up to the JEDEC-defined 3,200 Mbps. DDR4 has 2 times higher bandwidth than DDR3.

Complete multi-tasking with less energy.
Consumers want to be able to rely on excellent battery power to complete their tasks. Samsung PC DRAM provides longer time unplugged through lower power consumption. This enables extended battery life for notebooks while maintaining high performance.

Samsung DDR4 SODIMM and UDIMM consume less power with their unique 2xnm technology. Samsung’s 2xnm DDR4 operating at 1.2V achieves

Pateikta prekės informacija yra orientacinio pobūdžio. Techninės savybės, nuotraukos, aprašymai ir kaina gali keistis be išankstinio perspėjimo. Gamintojas ir pardavėjas neatsako už galimus duomenų neatitikimus ar tipografines klaidas. Prieš įsigyjant rekomenduojame pasitikrinti aktualią informaciją.

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approximately 26% higher performance/watt compared to 2xnm DDR3 operating at 1.5V.

Samsung also provides 2xnm LPDDR4 operating at 1.1V, achieving 37% increase in power efficiency than 2xnm LPDDR3 operating at 1.2V.

Double your capacity with the world’s 1st 8Gb chips.
The advancement in density has enabled Samsung to offer bigger capacity DRAM, delivering the faster data transmission speed that devices require today. PCs can benefit from high density DRAM by using fewer DRAM components, which leads to space saving.

Samsung DDR4 UDIMM can achieve the max capacity of 128GB using the world’s 1st 8Gb chips, which is 2 times bigger than that of DDR3’s 64GB made of 4Gb chips.

Techninė specifikacija

Features	
Internal memory	16 GB
Memory layout (modules x size)	1 x 16 GB
Internal memory type	DDR4
Component for	PC/Server
Memory form factor	288-pin DIMM
ECC	Yes
CAS latency	17
Memory clock speed	2400 MHz
Buffered memory type	Registered (buffered)
Memory voltage	1.2 V
Module configuration	2048M x 72
Row cycle time	17 ns
Refresh row cycle time	17 ns
Operational conditions	
Operating temperature (T-T)	0 - 85 °C
Sustainability	
Compliance certificates	RoHS
Weight & dimensions	
Width	133.3 mm
Depth	3.9 mm
Height	31.2 mm
Logistics data	
Harmonized System (HS) code	84733020
Other features	

Doesn't contain	Halogen

Gamintojo ir saugos informacija

GAMINTOJAS

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PLATINTOJAS

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